

# BTA201W series E

1 A Three-quadrant triacs high commutation

Rev. 03 — 13 March 2008

Product data sheet

## 1. Product profile

### 1.1 General description

Passivated guaranteed commutation triacs in a surface-mounted plastic package, intended for interfacing with low-power drivers, including microcontrollers.

### 1.2 Features

- Suitable for interfacing with low-power drivers, including microcontrollers
- SOT223 surface mounted

### 1.3 Applications

- Motor control
- Solenoid drivers

### 1.4 Quick reference data

- $I_{TSM} \leq 12.5$  A
- $I_{T(RMS)} \leq 1$  A
- $V_{DRM} \leq 600$  V (BTA201W-600E)
- $V_{DRM} \leq 800$  V (BTA201W-800E)
- $I_{GT} \leq 10$  mA (BTA201W-600E)
- $I_{GT} \leq 10$  mA (BTA201W-800E)
- $I_{GT} \geq 1$  mA (BTA201W-600E)
- $I_{GT} \geq 1$  mA (BTA201W-800E)

## 2. Pinning information

Table 1. Pinning

Pin	Description	Simplified outline	Symbol
1	main terminal 1 (T1)	<p>SOT223</p>	<p>sym051</p>
2	main terminal 2 (T2)		
3	gate (G)		
4	main terminal 2 (T2)		

### 3. Ordering information

**Table 2.** Ordering information

Type number	Package		Version
	Name	Description	
BTA201W-600E	SC-73	plastic surface-mounted package with increased heatsink; 4 leads	SOT223
BTA201W-800E			

### 4. Limiting values

**Table 3.** Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{\text{DRM}}$	repetitive peak off-state voltage	BTA201W-600E	[1] -	600	V
		BTA201W-800E	-	800	V
$I_{\text{T(RMS)}}$	RMS on-state current	full sine wave; $T_{\text{sp}} \leq 106\text{ }^{\circ}\text{C}$ ; see <a href="#">Figure 4</a> and <a href="#">5</a>	-	1	A
$I_{\text{TSM}}$	non-repetitive peak on-state current	full sine wave; $T_{\text{j}} = 25\text{ }^{\circ}\text{C}$ prior to surge; see <a href="#">Figure 2</a> and <a href="#">3</a>			
		$t = 20\text{ ms}$	-	12.5	A
		$t = 16.7\text{ ms}$	-	13.7	A
$I^2t$	$I^2t$ for fusing	$t_{\text{p}} = 10\text{ ms}$	-	0.78	$\text{A}^2\text{s}$
$di_{\text{T}}/dt$	rate of rise of on-state current	$I_{\text{TM}} = 1.5\text{ A}$ ; $I_{\text{G}} = 0.2\text{ A}$ ; $di_{\text{G}}/dt = 0.2\text{ A}/\mu\text{s}$	-	100	$\text{A}/\mu\text{s}$
$I_{\text{GM}}$	peak gate current		-	2	A
$P_{\text{GM}}$	peak gate power		-	5	W
$P_{\text{G(AV)}}$	average gate power	over any 20 ms period	-	0.1	W
$T_{\text{stg}}$	storage temperature		-40	+150	$^{\circ}\text{C}$
$T_{\text{j}}$	junction temperature		-	125	$^{\circ}\text{C}$

- [1] Although not recommended, off-state voltages up to 800 V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 6 A/ $\mu\text{s}$ .

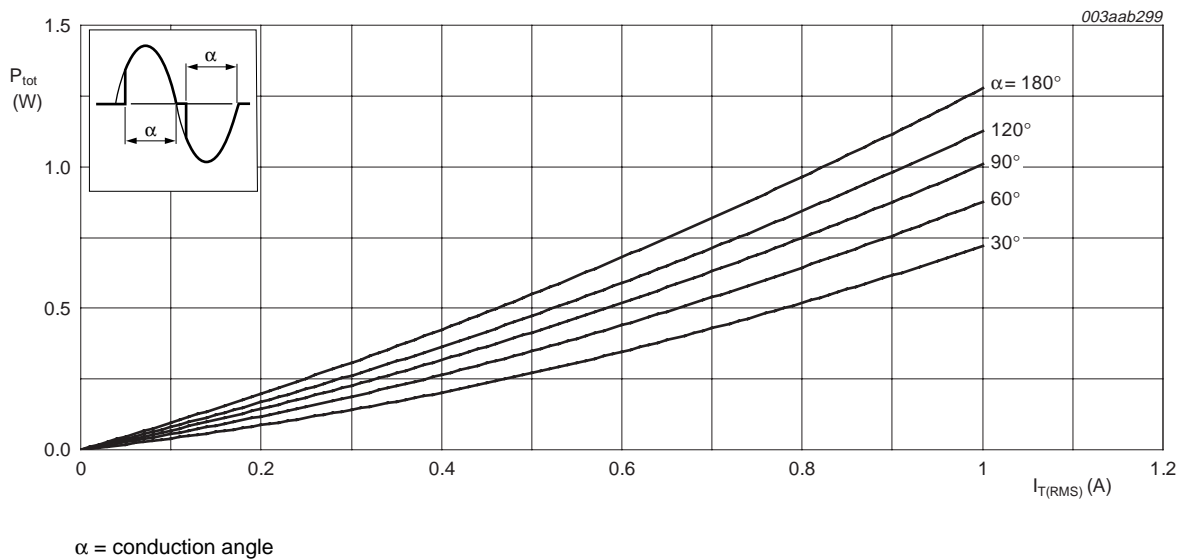


Fig 1. Total power dissipation as a function of RMS on-state current; maximum values

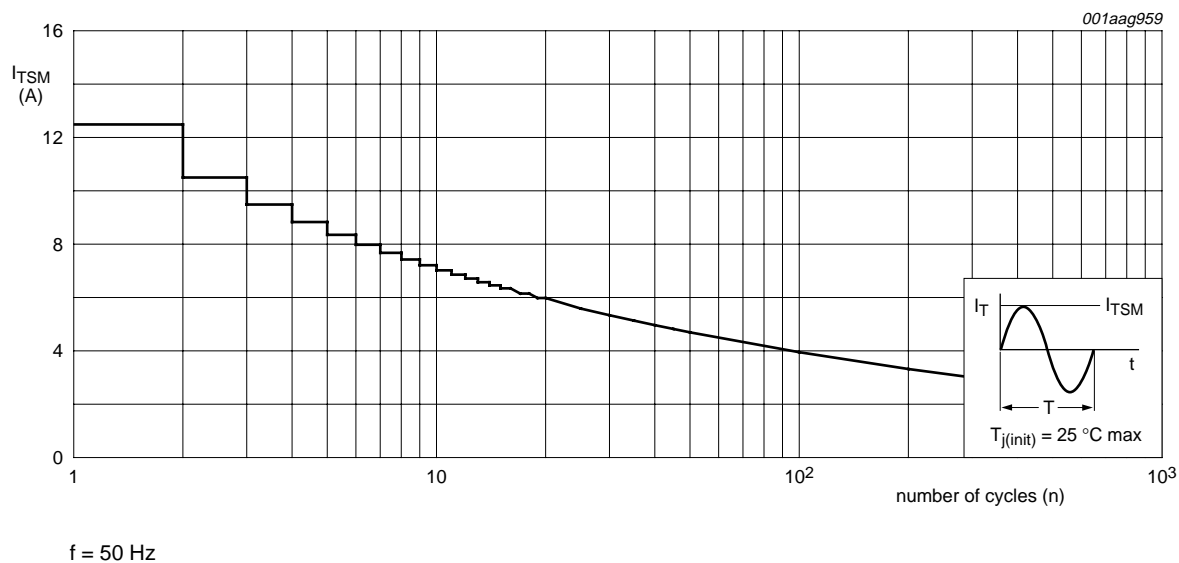


Fig 2. Non-repetitive peak on-state current as a function of the number of sinusoidal current cycles; maximum values

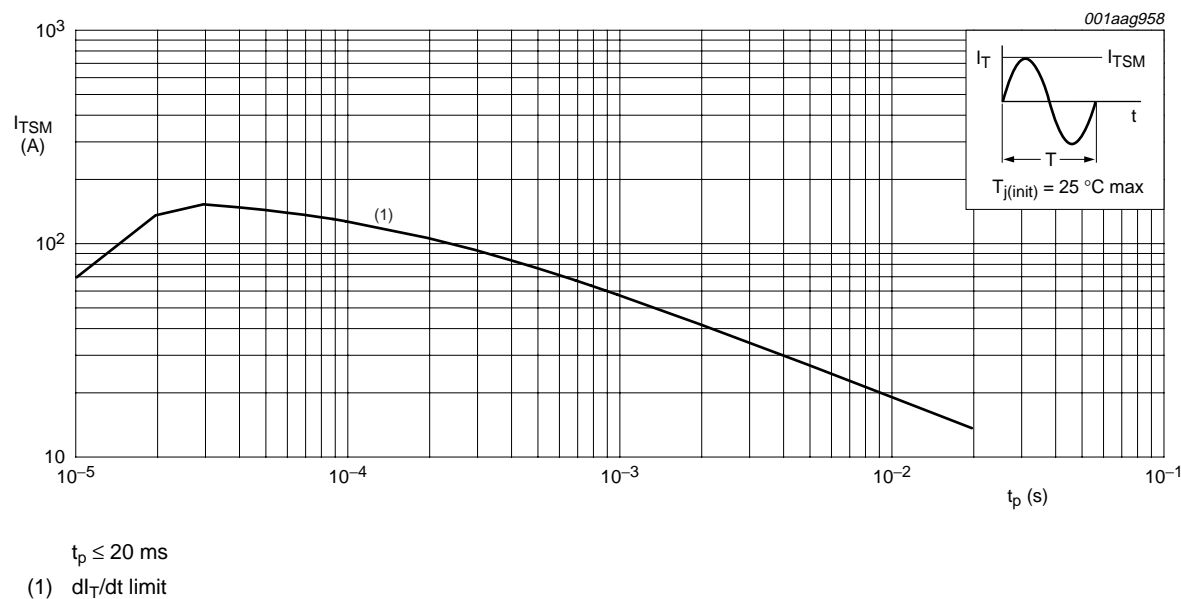


Fig 3. Non-repetitive peak on-state current as a function of pulse width; maximum values

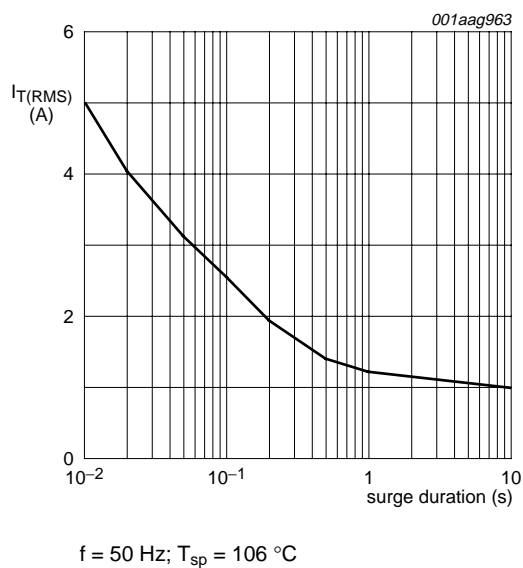


Fig 4. RMS on-state current as a function of surge duration; maximum values

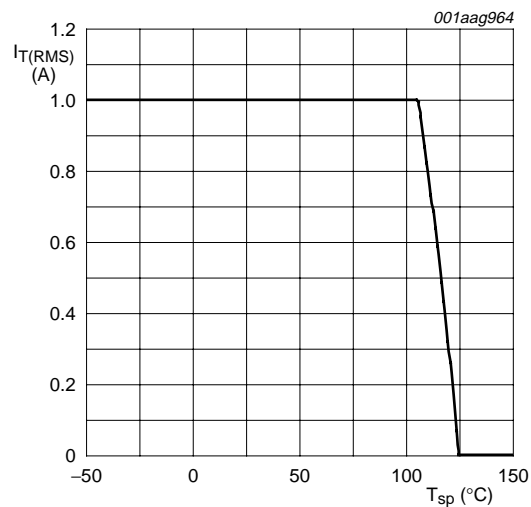


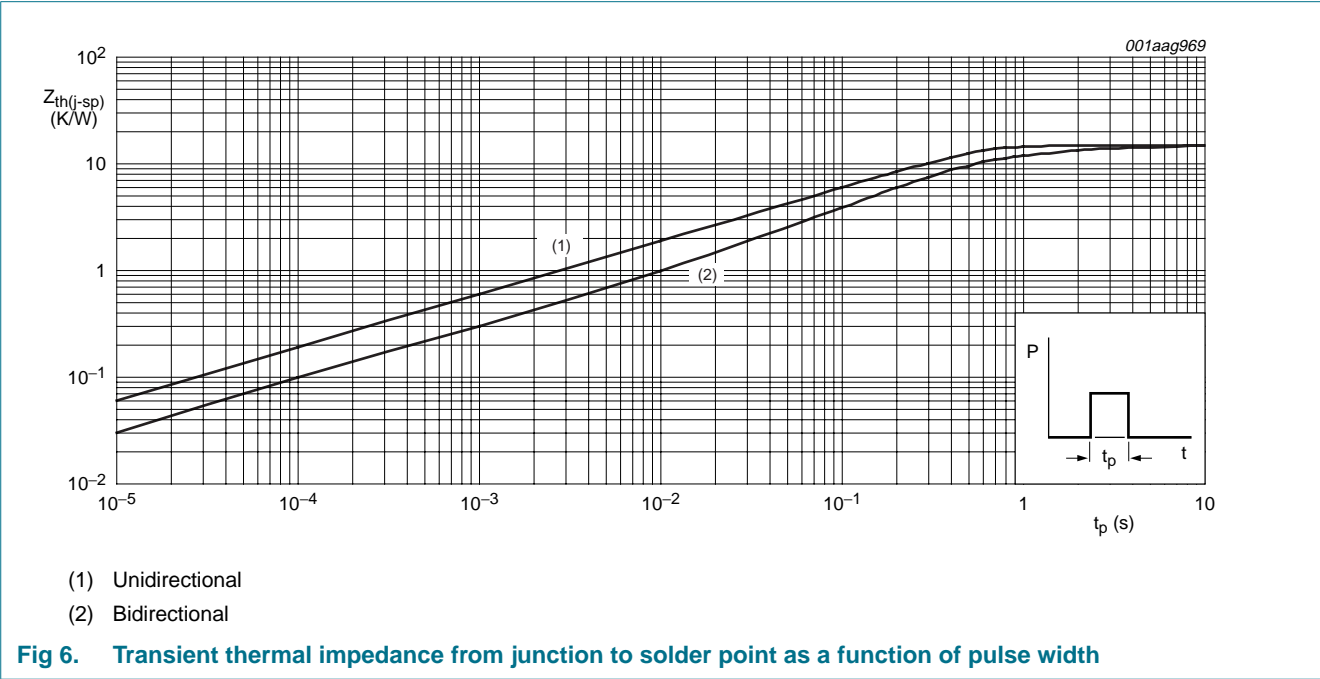
Fig 5. RMS on-state current as a function of solder point temperature; maximum values

5. Thermal characteristics

Table 4. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-sp)}$	thermal resistance from junction to solder point	see <a href="#">Figure 6</a>	-	-	15	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	minimum footprint; see <a href="#">Figure 14</a>	[1] -	156	-	K/W
		for pad area; see <a href="#">Figure 15</a>	[1] -	70	-	K/W

[1] Mounted on a printed-circuit board.



## 6. Static characteristics

**Table 5. Static characteristics**

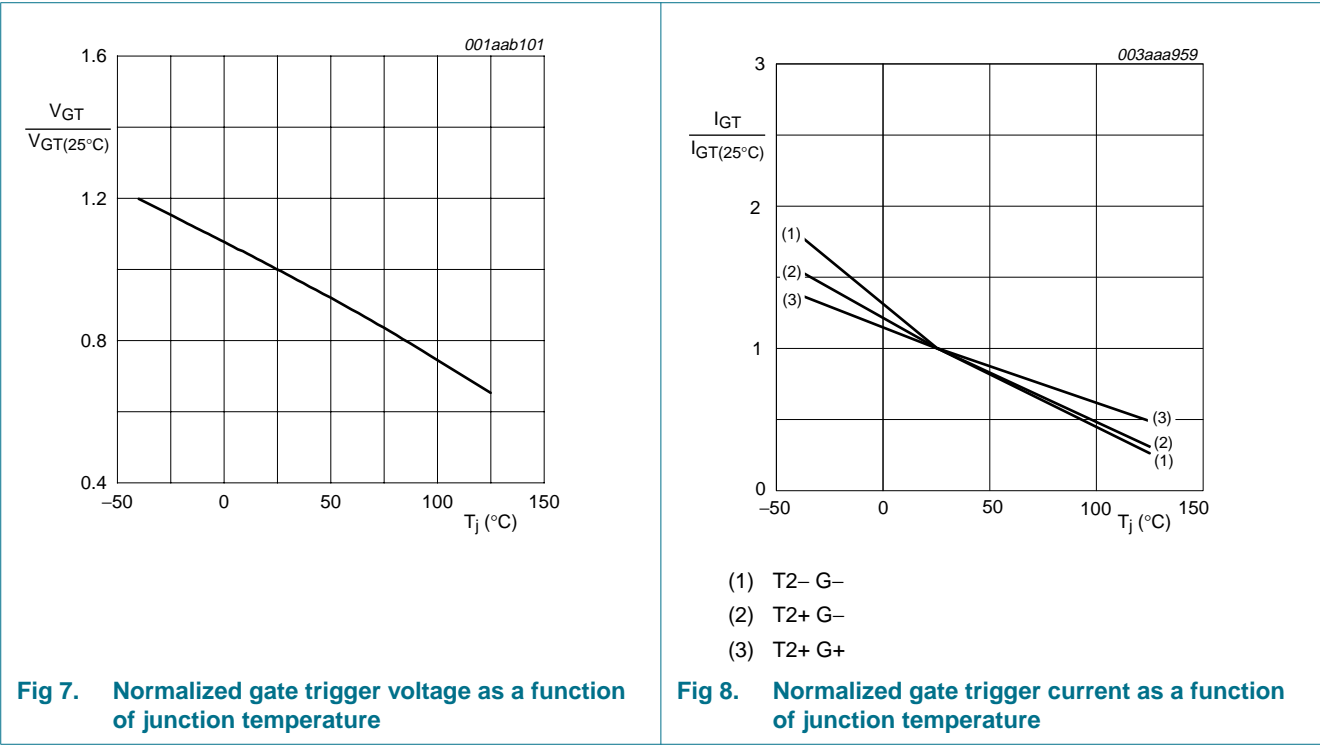
$T_j = 25\text{ °C}$  unless otherwise specified.

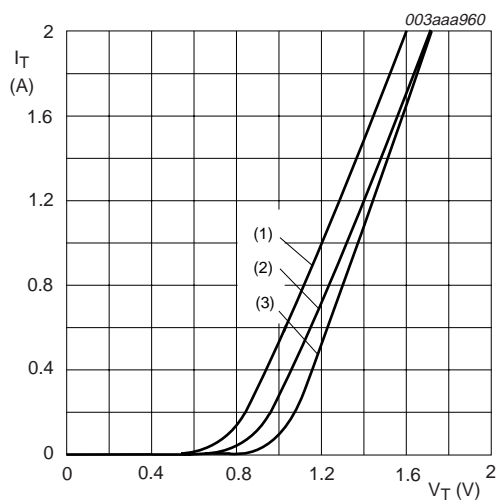
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>BTA201W-600E and BTA201W-800E</b>						
$I_{GT}$	gate trigger current	$V_D = 12\text{ V}$ ; $I_T = 0.1\text{ A}$ ; see <a href="#">Figure 8</a>				
		T2+ G+	1	-	10	mA
		T2+ G-	1	-	10	mA
		T2- G-	1	-	10	mA
$I_L$	latching current	$V_D = 12\text{ V}$ ; $I_G = 0.1\text{ A}$ ; see <a href="#">Figure 10</a>				
		T2+ G+	-	-	12	mA
		T2+ G-	-	-	20	mA
		T2- G-	-	-	12	mA
$I_H$	holding current	$V_D = 12\text{ V}$ ; $I_G = 0.1\text{ A}$ ; see <a href="#">Figure 11</a>	-	-	12	mA
$V_T$	on-state voltage	$I_T = 1.4\text{ A}$ ; see <a href="#">Figure 9</a>	-	1.2	1.5	V
$V_{GT}$	gate trigger voltage	$V_D = 12\text{ V}$ ; $I_T = 0.1\text{ A}$ ; see <a href="#">Figure 7</a>	-	0.7	1.5	V
		$V_D = 400\text{ V}$ ; $I_T = 0.1\text{ A}$ ; $T_j = 125\text{ °C}$	0.2	0.3	-	V
$I_D$	off-state current	$V_D = V_{DRM(max)}$ ; $T_j = 125\text{ °C}$	-	0.1	0.5	mA

7. Dynamic characteristics

Table 6. Dynamic characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
BTA201W-600E and BTA201W-800E						
$dV_D/dt$	rate of rise of off-state voltage	$V_{DM} = 0.67V_{DRM(max)}$ ; $T_j = 125\text{ }^{\circ}\text{C}$ ; exponential waveform; gate open circuit	600	-	-	$\text{V}/\mu\text{s}$
$di_{com}/dt$	rate of change of commutating current	$V_{DM} = 400\text{ V}$ ; $T_j = 125\text{ }^{\circ}\text{C}$ ; $I_{T(RMS)} = 4\text{ A}$ ; gate open circuit				
		$dV_{com}/dt = 20\text{ V}/\mu\text{s}$	2.5	-	-	$\text{A/ms}$
		$dV_{com}/dt = 10\text{ V}/\mu\text{s}$	3.5	-	-	$\text{A/ms}$
$t_{gt}$	gate-controlled turn-on time	$I_{TM} = 20\text{ A}$ ; $V_D = V_{DRM(max)}$ ; $I_G = 0.1\text{ A}$ ; $di_G/dt = 5\text{ A}/\mu\text{s}$	-	2	-	$\mu\text{s}$





- $V_o = 1.02$  V;  $R_s = 358$  m $\Omega$
- (1)  $T_j = 125$  °C; typical values
  - (2)  $T_j = 125$  °C; maximum values
  - (3)  $T_j = 25$  °C; maximum values

Fig 9. On-state current as a function of on-state voltage

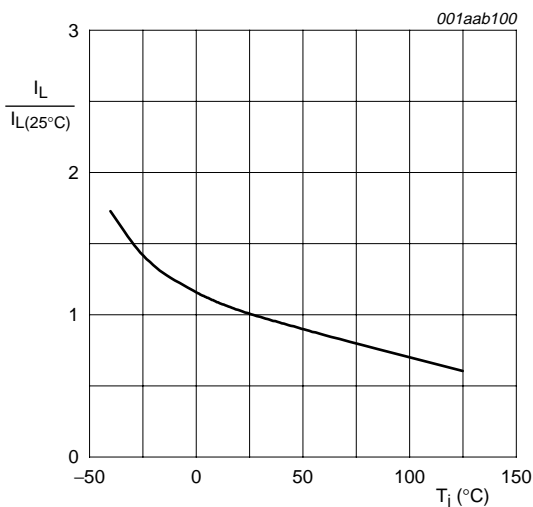


Fig 10. Normalized latching current as a function of junction temperature

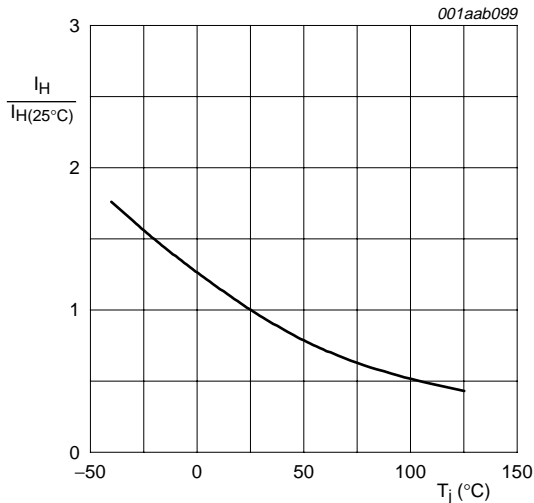
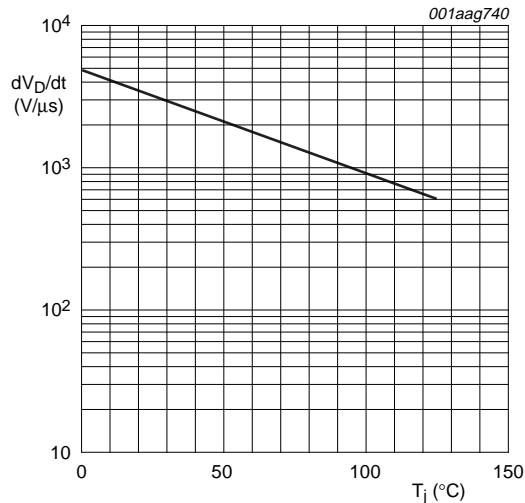


Fig 11. Normalized holding current as a function of junction temperature



Gate open circuit

Fig 12. Critical rate of rise of off-state voltage as a function of junction temperature; minimum values



8. Package outline

Plastic surface-mounted package with increased heatsink; 4 leads SOT223

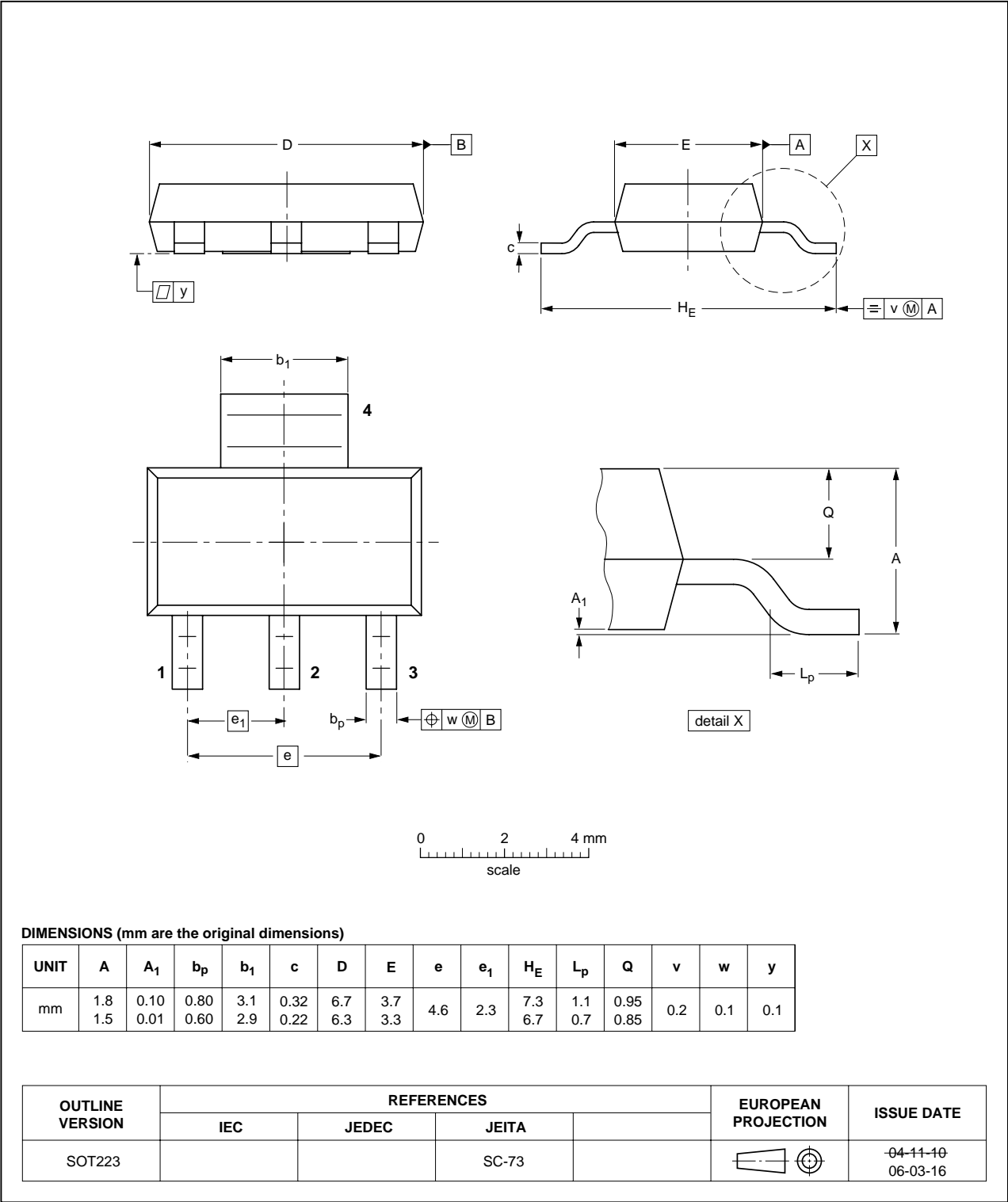
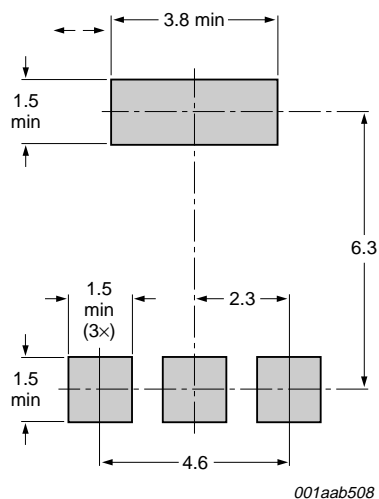


Fig 13. Package outline SOT223

## 9. Mounting

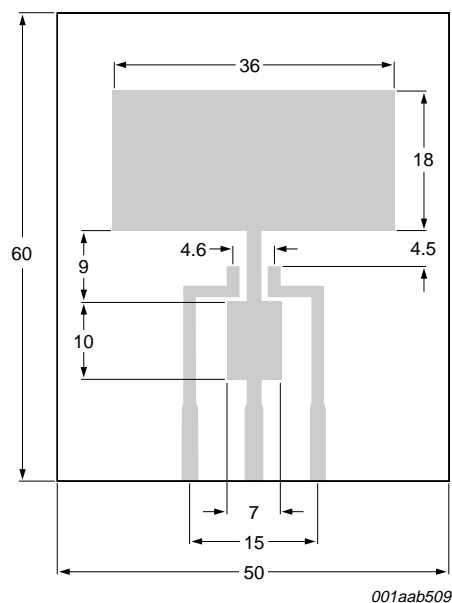
### 9.1 Mounting instructions



All dimensions are in mm

**Fig 14. Minimum footprint SOT223**

### 9.2 Printed-circuit board



All dimensions are in mm

Printed-circuit board: FR4 epoxy glass (1.6 mm thick), copper laminate (35  $\mu$ m thick)

**Fig 15. Printed-circuit board pad area SOT223**

## 10. Revision history

**Table 7. Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes
BTA201W_SER_E_3	20080313	Product data sheet	-	BTA201W_SER_E_2
Modifications:	<ul style="list-style-type: none"><li>• <a href="#">Section 1.4 "Quick reference data" on page 1</a>: Updated with minimum <math>I_{GT}</math> values added.</li><li>• <a href="#">Table 3 "Limiting values" on page 2</a>: <math>I^2t</math> condition, <math>t_p</math>; symbol update.</li><li>• <a href="#">Table 5 "Static characteristics" on page 6</a>: Minimum <math>I_G</math> values added.</li></ul>			
BTA201W_SER_E_2	20070917	Product data sheet	-	BTA201W_SER_E_1
Modifications:	<ul style="list-style-type: none"><li>• The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.</li><li>• Legal texts have been adapted to the new company name where appropriate.</li><li>• Descriptive titles have been corrected.</li><li>• Table 3 "Limiting values" on page 2: <math>di_T/dt</math> updated</li><li>• Table 6 "Dynamic characteristics" on page 7: <math>dV_D/dt</math> updated</li><li>• Figure "Critical rate of rise of off-state voltage as a function of junction temperature; minimum values" on page 8: graph updated</li></ul>			
BTA201W_SER_E_1	20060207	Product data sheet	-	-

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Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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